

SHD280502

TECHNICAL DATA DATA SHEET 4065, REV. -

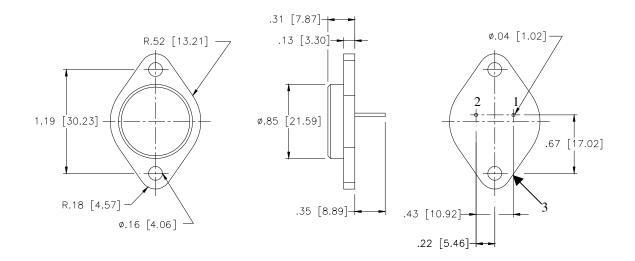
HERMETIC POWER MOSFET N-CHANNEL

DESCRIPTION: A 100-VOLT, 0.055-OHM MOSFET IN A HERMETIC TO-3 / TO-204AA PACKAGE.

MAXIMUM RATINGS ALL RATINGS ARE AT $T_A = 25^{\circ}$ C UNLESS OTHERWISE SPECIFIED.							
RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS		
GATE TO SOURCE VOLTAGE	V _{GS}	-	-	±20	Volts		
CONTINUOUS DRAIN CURRENT @ $T_c = 25^{\circ}C$		-	-	38	Amps		
$@ T_{c} = 100^{\circ}C$	U			24	1		
PULSED DRAIN CURRENT $@ T_c = 25^{\circ}C$	I _{DM}	-	-	150	Amps(pk)		
OPERATING AND STORAGE TEMPERATURE	T _{OP} /T _{STG}	-55	-	+150	°C		
TERMAL RESISTANCE JUNCTION TO CASE	R _{0JC}	-	-	0.83	°C/W		
TOTAL DEVICE DISSIPATION @ $T_c = 25^{\circ}C$	PD	-	-	150	Watts		
	5		I		I		
		100			Malla.		
DRAIN TO SOURCE BREAKDOWN VOLTAGE	BV _{DSS}	100	-	-	Volts		
$V_{GS} = 0V, I_D = 1.0mA$	N/	2.0		4.0			
GATE THRESHOLD VOLTAGE $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ DRAIN TO SOURCE ON STATE RESISTANCE	V _{GS(TH)}	2.0	-	4.0			
DRAIN TO SOURCE ON STATE RESISTANCE $V_{GS} = 10Vdc, I_D = 24A$	Б			0.055	0		
PULSE TEST, t \leq 300 μ s, DUTY CYCLE d \leq 2%	R _{DS(ON)}	-	-	0.055	Ω		
ZERO GATE VOLTAGE DRAIN CURRENT		_					
$V_{DS} = 0.8 \text{xMax}$. Rating, $V_{GS} = 0 \text{Vdc}$	I _{DSS}	-	-	25	μA		
$V_{DS} = 0.8 \text{ Max}$. Rating	'DSS			20	μΛ		
$V_{GS} = 0Vdc, T_J = 125^{\circ}C$				250			
GATE TO BODY LEAKAGE CURRENT $V_{GS} = \pm 20 \text{ Vdc},$	I _{GSS}	-	-	±100	nA		
	-000						
TOTAL GATE CHARGE V _{GS} = 10 Vdc	Qg	50	-	125	nC		
GATE TO SOURCE CHARGE $V_{DS} = 0.5V$ Max. Rating,	Q _{gs}	8		22			
GATE TO DRAIN CHARGE $I_D = 38A$	Q _{gd}	25		65			
TURN ON DELAY TIME $V_{DD} = 50V$,	t _{d(ON)}	-	-	35	nsec		
RISE TIME $I_D = 38A$,	t _r			190			
TURN OFF DELAY TIME $R_G = 2.35\Omega$	t _{d(OFF)}			170			
FALL TIME	t _f			130			
FORWARD VOLTAGE $T_J = 25^{\circ}C$, $I_S = 38A$, $V_{GS} = 0V$	V _{SD}	-	-	1.9	Volts		
PULSE TEST, t \leq 300 μ s, DUTY CYCLE d \leq 2%				500			
REVERSE RECOVERY TIME $I_F = 38A$	t _{rr}	-	-	500	nsec		
REVERSE RECOVERY CHARGE di/dt = 100A/µsec			——				
$V_{DD} \le 30V$	Q _{rr}	-	-	2.9	μC		
INPUT CAPACITANCE $V_{DS} = 25 \text{ Vdc},$	C _{iss}	-	3700	-	pF		
OUTPUT CAPACITANCE $V_{GS} = 0 Vdc,$	Coss		1100				
REVERSE TRANSFER CAPACITANCEf = 1 MHz	C _{rss}		200				

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MECHANICAL DIMENSIONS: in Inches



PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET	SOURCE	GATE	DRAIN
TO-3 / TO-204 AA			
PACKAGE			



TECHNICAL DATA

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